8-CHANNEL ANALOG MULTIPLEXER/DEMULTIPLEXER WITH LATCH

FEATURES

- Wide analog input voltage range: ± 5 V
- Low "ON" resistance:
  80 Ω (typ.) at $V_{CC} - V_{EE}$ = 4.5 V
  70 Ω (typ.) at $V_{CC} - V_{EE}$ = 6.0 V
  60 Ω (typ.) at $V_{CC} - V_{EE}$ = 9.0 V
- Logic level translation:
  to enable 5 V logic to communicate with ± 5 V analog signals
- Typical "break before make" built in
- Address latches provided
- Output capability: non-standard
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT4351 are high-speed Si-gate CMOS devices. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT4351 are 8-channel analog multiplexers/demultiplexers with three select inputs (S_0 to S_2), two enable inputs ($\overline{E}_1$ and E_2), a latch enable input ($\overline{LE}$), eight independent inputs/outputs (Y_0 to Y_7) and a common input/output (Z).

With $\overline{E}_1$ LOW and E_2 is HIGH, one of the eight switches is selected (low impedance ON-state) by S_0 to S_2. The data at the select inputs may be latched by using the active LOW latch enable input ($\overline{LE}$). When $\overline{LE}$ is HIGH the latch is transparent. When either of the two enable inputs, $\overline{E}_1$ (active LOW) and E_2 (active HIGH), is inactive, all 8 analog switches are turned off.

(continued on next page)

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t_{PZH}/ t_{PZL}	turn "ON" time $\overline{E}_1$, E_2 or S_n to V_{OS}	C_L = 15 pF, R_L = 1 kΩ, V_{CC} = 5 V	27	35	ns
t_{PHZ}/ t_{PLZ}	turn "OFF" time $\overline{E}_1$, E_2 or S_n to V_{OS}		21	23	ns
C_I	input capacitance		3.5	3.5	pF
C_{PD}	power dissipation capacitance per switch	notes 1 and 2	25	25	pF
C_S	max. switch capacitance independent (Y) common (Z)		5 25	5 25	pF pF

V_{EE} = GND = 0 V; T_{amb} = 25 °C; $t_r = t_f$ = 6 ns

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):
   $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma\{(C_L + C_S) \times V_{CC}^2 \times f_o\}$ where:
   f_i = input frequency in MHz
   f_o = output frequency in MHz
   $\Sigma\{(C_L + C_S) \times V_{CC}^2 \times f_o\}$ = sum of outputs
   C_L = output load capacitance in pF
   C_S = max. switch capacitance in pF
   V_{CC} = supply voltage in V
2. For HC the condition is V_I = GND to V_{CC}
   For HCT the condition is V_I = GND to V_{CC} − 1.5 V

PACKAGE OUTLINES

20-lead DIL; plastic (SOT146).
20-lead mini-pack; plastic (SO20; SOT163A).

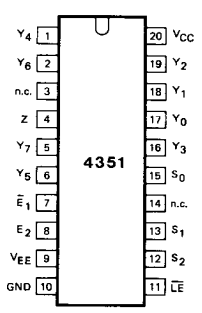
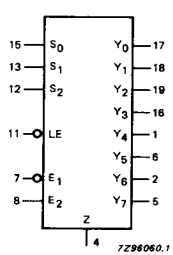


Fig. 1 Pin configuration.



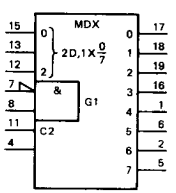


Fig. 3 IEC logic symbol.

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
4	Z	common
3, 14	n.c.	not connected
7	$\overline{E}_1$	enable input (active LOW)
8	E_2	enable input (active HIGH)
9	V_{EE}	negative supply voltage
10	GND	ground (0 V)
11	$\overline{LE}$	latch enable input (active LOW)
15, 13, 12	S_0 to S_2	select inputs
17, 18, 19, 16, 1, 6, 2, 5	Y_0 to Y_7	independent inputs/outputs
20	V_{CC}	positive supply voltage

FUNCTION TABLE

INPUTS						CHANNEL ON
$\overline{E}_1$	E_2	$\overline{LE}$	S_2	S_1	S_0	
H	X	X	X	X	X	none
X	L	X	X	X	X	none
L	H	H	L	L	L	Y_0
L	H	H	L	L	H	Y_1
L	H	H	L	H	L	Y_2
L	H	H	L	H	H	Y_3
L	H	H	H	L	L	Y_4
L	H	H	H	L	H	Y_5
L	H	H	H	H	L	Y_6
L	H	H	H	H	H	Y_7
L	H	L	X	X	X	*
X	X	↓	X	X	X	**

H = HIGH voltage level
L = LOW voltage level
X = don't care
↓ = HIGH-to-LOW $\overline{LE}$ transition

* Last selected channel "ON".
** Selected channels latched.

APPLICATIONS

- **Analog multiplexing and demultiplexing**
- **Digital multiplexing and demultiplexing**
- **Signal gating**

GENERAL DESCRIPTION

V_{CC} and GND are the supply voltage pins for the digital control inputs (S_0 to S_2, $\overline{LE}$, $\overline{E}_1$ and E_2). The V_{CC} to GND ranges are 2.0 to 10.0 V for HC and 4.5 to 5.5 V for HCT. The analog inputs/outputs (Y_0 to Y_7, and Z) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit. $V_{CC} - V_{EE}$ may not exceed 10.0 V.

For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to GND (typically ground).

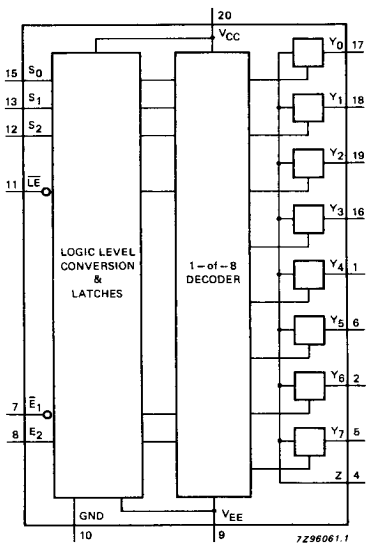


Fig. 4 Functional diagram.

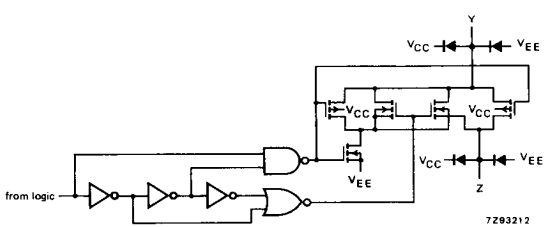


Fig. 5 Schematic diagram (one switch).

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Voltages are referenced to V_{EE} = GND (ground = 0 V)

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	CONDITIONS
V_{CC}	DC supply voltage	−0.5	+11.0	V	
$\pm I_{IK}$	DC digital input diode current		20	mA	for $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V
$\pm I_{SK}$	DC switch diode current		20	mA	for $V_S < -0.5$ V or $V_S > V_{CC} + 0.5$ V
$\pm I_S$	DC switch current		25	mA	for -0.5 V $< V_S < V_{CC} + 0.5$ V
$\pm I_{EE}$	DC V_{EE} current		20	mA	
$\pm I_{CC}$; $\pm I_{GND}$	DC V_{CC} or GND current		50	mA	
T_{stg}	storage temperature range	−65	+150	°C	
P_{tot}	power dissipation per package				for temperature range: −40 to +125 °C 74HC/HCT
	plastic DIL		750	mW	above +70 °C: derate linearly with 12 mW/K
	plastic mini-pack (SO)		500	mW	above +70 °C: derate linearly with 8 mW/K
P_S	power dissipation per switch		100	mW	

Note to ratings

To avoid drawing V_{CC} current out of terminal Z, when switch current flows in terminals Y_n, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Y_n. In this case there is no limit for the voltage drop across the switch, but the voltages at Y_n and Z may not exceed V_{CC} or V_{EE}.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	74HC			74HCT			UNIT	CONDITIONS
		min.	typ.	max.	min.	typ.	max.		
V_{CC}	DC supply voltage V_{CC}–GND	2.0	5.0	10.0	4.5	5.0	5.5	V	see Figs 6 and 7
V_{CC}	DC supply voltage V_{CC}–V_{EE}	2.0	5.0	10.0	2.0	5.0	10.0	V	see Figs 6 and 7
V_I	DC input voltage range	GND		V_{CC}	GND		V_{CC}	V	
V_S	DC switch voltage range	V_{EE}		V_{CC}	V_{EE}		V_{CC}	V	
T_{amb}	operating ambient temperature range	−40		+85	−40		+85	°C	see DC and AC CHARACTERISTICS
T_{amb}	operating ambient temperature range	−40		+125	−40		+125	°C	
t_r, t_f	input rise and fall times		6.0	1000 500 400 250		6.0	500	ns	V_{CC} = 2.0 V V_{CC} = 4.5 V V_{CC} = 6.0 V V_{CC} = 10.0 V

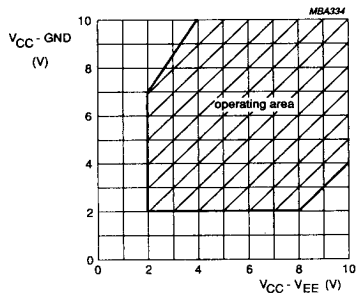


Fig. 6 Guaranteed operating area as a function of the supply voltages for 74HC4351.

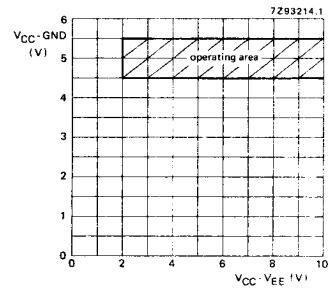


Fig. 7 Guaranteed operating area as a function of the supply voltages for 74HCT4351.

DC CHARACTERISTICS FOR 74HC/HCT

For 74HC: V_{CC} – GND or V_{CC} – V_{EE} =2.0, 4.5, 6.0 and 9.0 V
For 74HCT: V_{CC} – GND =4.5 and 5.5 V; V_{CC} – V_{EE} =2.0, 4.5, 6.0 and 9.0 V

SYMBOL	PARAMETER	T_{amb} (°C) 74HC/HCT +25 min.	+25 typ.	+25 max.	–40 to +85 min.	–40 to +85 max.	–40 to +125 min.	–40 to +125 max.	UNIT	TEST CONDITIONS V_{CC} V	V_{EE} V	I_S μA	V_{is}	V_I
R_{ON}	ON resistance (rail)		– 100 90 70	– 180 160 130		– 225 200 165		– 270 240 195	Ω Ω Ω Ω	2.0 4.5 6.0 4.5	0 0 0 –4.5	100 1000 1000 1000	V_{CC} to V_{EE}	V_{IN} or V_{IL}
R_{ON}	ON resistance (rail)		150 80 70 60	– 140 120 105		– 175 150 130		– 210 180 160	Ω Ω Ω Ω	2.0 4.5 6.0 4.5	0 0 0 –4.5	100 1000 1000 1000	V_{EE}	V_{IH} or V_{IL}
R_{ON}	ON resistance (rail)		150 90 80 65	– 160 140 120		– 200 175 150		– 240 210 180	Ω Ω Ω Ω	2.0 4.5 6.0 4.5	0 0 0 –4.5	100 1000 1000 1000	V_{CC}	V_{IH} or V_{IL}
ΔR_{ON}	maximum Δ ON resistance between any two channels		– 9 8 6						Ω Ω Ω Ω	2.0 4.5 6.0 4.5	0 0 0 –4.5		V_{CC} to V_{EE}	V_{IH} or V_{IL}

Notes to DC characteristics

1. At supply voltages (V_{CC} – V_{EE}) approaching 2.0 V the analog switch ON-resistance becomes extremely non-linear. There it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
2. For test circuit measuring R_{ON} see Fig. 8.

DC CHARACTERISTICS FOR 74HC

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS			
		74HC											
		+25			−40 to +85		−40 to +125			V_{CC} V	V_{EE} V	V_I	OTHER
		min.	typ.	max.	min.	max.	min.	max.					
V_{IH}	HIGH level input voltage	1.5 3.15 4.2 6.3	1.2 2.4 3.2 4.7		1.5 3.15 4.2 6.3		1.5 3.15 4.2 6.3		V	2.0 4.5 6.0 9.0			
V_{IL}	LOW level input voltage		0.8 2.1 2.8 4.3	0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7	V	2.0 4.5 6.0 9.0			
$\pm I_I$	input leakage current			0.1 0.2		1.0 2.0		1.0 2.0	μA	6.0 10.0	0 0	V_{CC} or GND	
$\pm I_S$	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	0	V_{IH} or V_{IL}	$\lvert V_S \rvert = V_{CC} - V_{EE}$ (see Fig. 10)
$\pm I_S$	analog switch OFF-state current all channels			0.4		4.0		4.0	μA	10.0	0	V_{IH} or V_{IL}	$\lvert V_S \rvert = V_{CC} - V_{EE}$ (see Fig. 10)
$\pm I_S$	analog switch ON-state current			0.4		4.0		4.0	μA	10.0	0	V_{IH} or V_{IL}	$\lvert V_S \rvert = V_{CC} - V_{EE}$ (see Fig. 11)
I_{CC}	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	6.0 10.0	0 0	V_{CC} or GND	$V_{is} = V_{EE}$ or V_{CC}; $V_{os} = V_{CC}$ or V_{EE}

AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f$ = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS		
		74HC										
		+25			–40 to +85		–40 to +125			V_{CC} V	V_{EE} V	OTHER
		min.	typ.	max.	min.	max.	min.	max.				
t_{PHL}/ t_{PLH}	propagation delay V_{is} to V_{os}		14 5 4 4	60 12 10 8		75 15 13 10		90 18 15 12	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = ∞; C_L = 50 pF (see Fig. 17)
t_{PZH}/ t_{PZL}	turn "ON" time $\overline{E}_1$ to V_{os}		85 31 25 28	300 60 51 55		375 75 64 69		450 90 77 83	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PZH}/ t_{PZL}	turn "ON" time E_2 to V_{os}		85 31 25 25	300 60 51 55		375 75 64 69		450 90 77 83	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PZH}/ t_{PZL}	turn "ON" time $\overline{LE}$ to V_{os}		91 33 26 27	300 60 51 55		375 75 64 69		450 90 77 83	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PZH}/ t_{PZL}	turn "ON" time S_n to V_{os}		88 32 26 25	300 60 51 50		375 75 64 63		450 90 77 75	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PHZ}/ t_{PLZ}	turn "OFF" time $\overline{E}_1$ to V_{os}		69 25 20 20	250 50 43 40		315 63 54 50		375 75 64 60	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PHZ}/ t_{PLZ}	turn "OFF" time E_2 to V_{os}		72 26 21 19	250 50 43 40		315 63 54 50		375 75 64 60	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PHZ}/ t_{PLZ}	turn "OFF" time $\overline{LE}$ to V_{os}		83 30 24 26	275 55 47 45		345 69 59 56		415 83 71 68	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PHZ}/ t_{PLZ}	turn "OFF" time S_n to V_{os}		80 29 23 24	275 55 47 48		345 69 59 60		415 83 71 72	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{su}	set-up time S_n to $\overline{LE}$	60 12 10 18	17 6 5 9			75 15 13 23		90 18 15 27	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 19)
t_h	hold time S_n to $\overline{LE}$	5 5 5 5	–8 –3 –2 –4			5 5 5 5		5 5 5 5	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 19)
t_W	$\overline{LE}$ minimum pulse width HIGH	100 20 17 25	11 1 3 7			125 25 21 31		150 30 26 38	ns	2.0 4.5 6.0 4.5	0 0 0 –4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 19)

DC CHARACTERISTICS FOR 74HCT

Voltages are referenced to GND (ground = 0)

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS			
		74HCT											
		+25			−40 to +85		−40 to +125			V_{CC} V	V_{EE} V	V_I	OTHER
		min.	typ.	max.	min.	max.	min.	max.					
V_{IH}	HIGH level input voltage	2.0	1.6		2.0		2.0		V	4.5 to 5.5			
V_{IL}	LOW level input voltage		1.2	0.8		0.8		0.8	V	4.5 to 5.5			
$\pm I_I$	input leakage current			0.1		1.0		1.0	μA	5.5	0	V_{CC} or GND	
$\pm I_S$	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	0	V_{IH} or V_{IL}	$\lvert V_S \rvert = V_{CC} - V_{EE}$ (see Fig. 10)
$\pm I_S$	analog switch OFF-state current all channels			0.4		4.0		4.0	μA	10.0	0	V_{IH} or V_{IL}	$\lvert V_S \rvert = V_{CC} - V_{EE}$ (see Fig. 10)
$\pm I_S$	analog switch ON-state current			0.4		4.0		4.0	μA	10.0	0	V_{IH} or V_{IL}	$\lvert V_S \rvert = V_{CC} - V_{EE}$ (see Fig. 11)
I_{CC}	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	5.5 5.0	0 −5.0	V_{CC} or GND	$V_{is} = V_{EE}$ or V_{CC}; $V_{os} = V_{CC}$ or V_{EE}
ΔI_{CC}	additional quiescent supply current per input pin for unit load coefficient is 1 (note 1)		100	360		450		490	μA	4.5 to 5.5	0	V_{CC} −2.1 V	other inputs at V_{CC} or GND

Note to HCT types

1. The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given here.
   To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
$\overline{E}_1$, E_2	0.50
S_n	0.50
$\overline{CE}$	1.5

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f$ = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS		
		74HCT										
		+25			−40 to +85		−40 to +125			V_{CC} V	V_{EE} V	OTHER
		min.	typ.	max.	min.	max.	min.	max.				
t_{PHL}/t_{PLH}	propagation delay V_{is} to V_{os}		6 4	12 8		15 10		18 12	ns	4.5 4.5	0 −4.5	$R_L = \infty$; C_L = 50 pF (see Fig. 17)
t_{PZH}/t_{PZL}	turn "ON" time $\overline{E}_1$ to V_{os}		40 31	75 60		94 75		113 90	ns	4.5 4.5	0 −4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PZH}/t_{PZL}	turn "ON" time E_2 to V_{os}		35 26	70 50		88 63		105 75	ns	4.5 4.5	0 −4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PZH}/t_{PZL}	turn "ON" time $\overline{LE}$ to V_{os}		42 37	75 60		94 75		113 90	ns	4.5 4.5	0 −4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PZH}/t_{PZL}	turn "ON" time S_n to V_{os}		39 30	75 60		94 75		113 90	ns	4.5 4.5	0 −4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PHZ}/t_{PLZ}	turn "OFF" time $\overline{E}_1$ to V_{os}		27 20	55 40		69 50		83 60	ns	4.5 4.5	0 −4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PHZ}/t_{PLZ}	turn "OFF" time E_2 to V_{os}		32 26	60 50		75 63		90 75	ns	4.5 4.5	0 −4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PHZ}/t_{PLZ}	turn "OFF" time $\overline{LE}$ to V_{os}		33 30	60 55		75 69		90 83	ns	4.5 4.5	0 −4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{PHZ}/t_{PLZ}	turn "OFF" time S_n to V_{os}		33 29	65 55		81 69		98 83	ns	4.5 4.5	0 −4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 18)
t_{su}	set-up time S_n to $\overline{LE}$	12 14	6 7			15 18		18 21	ns	4.5 4.5	0 −4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 19)
t_h	hold time S_n to $\overline{LE}$	5 5	−1 −2			5 5		5 5	ns	4.5 4.5	0 −4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 19)
t_W	$\overline{LE}$ minimum pulse width HIGH	25 25	13 13			31 31		38 38	ns	4.5 4.5	0 −4.5	R_L = 1 kΩ; C_L = 50 pF (see Fig. 19)

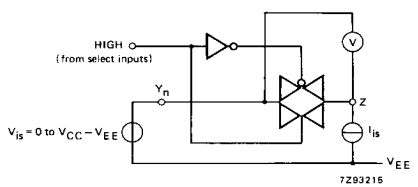


Fig. 8 Test circuit for measuring R_{ON}.

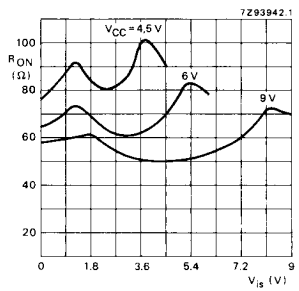


Fig. 9 Typical R_{ON} as a function of input voltage V_{is} for V_{is} = 0 to $V_{CC} - V_{EE}$.

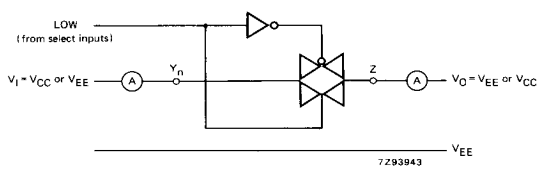


Fig. 10 Test circuit for measuring OFF-state current.

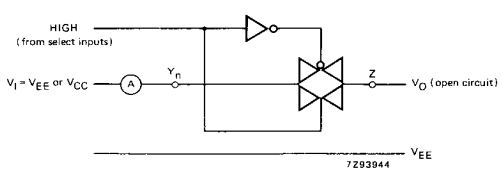


Fig. 11 Test circuit for measuring ON-state current.

ADDITIONAL AC CHARACTERISTICS FOR 74HC/HCT

Recommended conditions and typical values

GND = 0 V; T_{amb} = 25 °C

SYMBOL	PARAMETER	typ.	UNIT	V_{CC} V	V_{EE} V	$V_{is(p-p)}$ V	CONDITIONS
	sine-wave distortion f = 1 kHz	0.04 0.02	% %	2.25 4.5	−2.25 −4.5	4.0 8.0	R_L = 10 kΩ; C_L = 50 pF (see Fig. 14)
	sine-wave distortion f = 10 kHz	0.12 0.06	% %	2.25 4.5	−2.25 −4.5	4.0 8.0	R_L = 10 kΩ; C_L = 50 pF (see Fig. 14)
	switch "OFF" signal feed-through	−50 −50	dB dB	2.25 4.5	−2.25 −4.5	note 1	R_L = 600 Ω; C_L = 50 pF (see Figs 12 and 15)
$V_{(p-p)}$	crosstalk voltage between control and any switch (peak-to-peak value)	120 220	mV mV	4.5 4.5	0 −4.5		R_L = 600 Ω; C_L = 50 pF; f = 1 MHz (E_1, E_2 or S_n, square-wave between V_{CC} and GND, t_r = t_f = 6 ns) (see Fig. 16)
f_{max}	minimum frequency response (−3dB)	160 170	MHz MHz	2.25 4.5	−2.25 −4.5	note 2	R_L = 50 Ω; C_L = 10 pF (see Figs 13 and 14)
C_S	maximum switch capacitance independent (Y) common (Z)	5 25	pF pF				

Notes to AC characteristics

General note

V_{is} is the input voltage at a Y_n or Z terminal, whichever is assigned as an input.
V_{os} is the output voltage at a Y_n or Z terminal, whichever is assigned as an output.

Notes

1. Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).
2. Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).

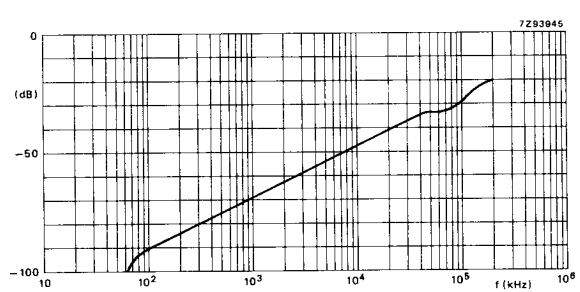
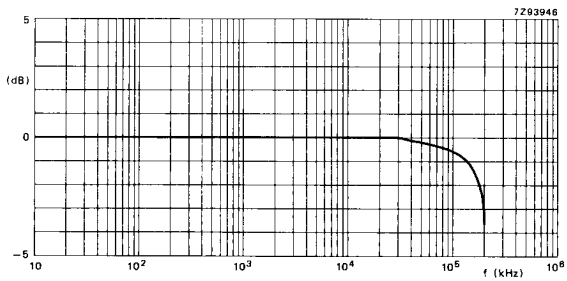


Fig. 12 Typical switch "OFF" signal feed-through as a function of frequency.



Note to Figs 12 and 13

Test conditions:
V_{CC} = 4.5 V; GND = 0 V; V_{EE} = −4.5 V;
R_L = 50 Ω; R_{source} = 1 kΩ.

Fig. 13 Typical frequency response.

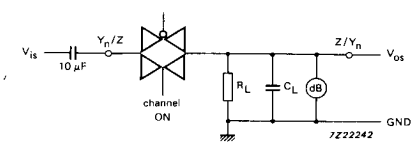


Fig. 14 Test circuit for measuring sine-wave distortion and minimum frequency response.

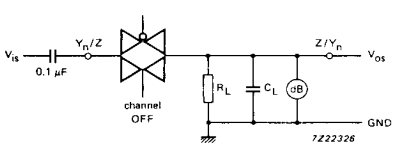


Fig. 15 Test circuit for measuring switch "OFF" signal feed-through.

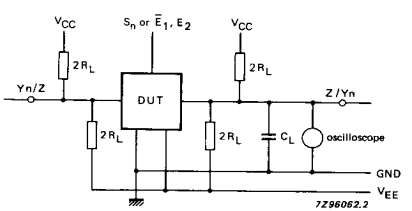
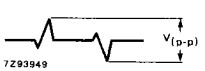


Fig. 16 Test circuit for measuring crosstalk between control and any switch.

Note to Fig. 16

The crosstalk is defined as follows (oscilloscope output):



AC WAVEFORMS

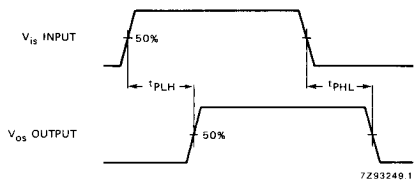


Fig. 17 Waveforms showing the input (V_{is}) to output (V_{os}) propagation delays.

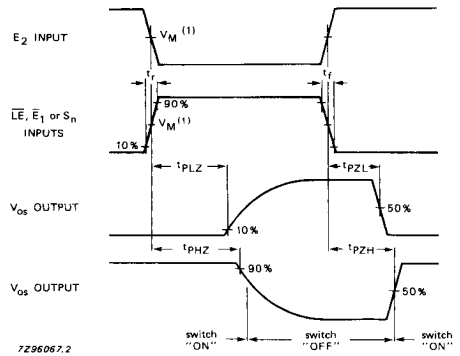


Fig. 18 Waveforms showing the turn-ON and turn-OFF times.

Note to Fig. 18

(1) HC : V_M = 50%; V_I = GND to V_{CC}.
HCT: V_M = 1.3 V; V_I = GND to 3 V.

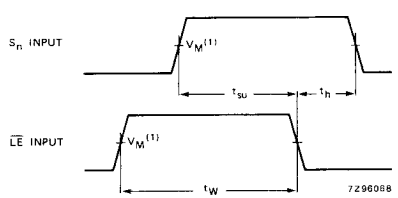


Fig. 19 Waveforms showing the set-up and hold times from S_n inputs to $\overline{LE}$ input, and minimum pulse width of $\overline{LE}$.

Note to Fig. 19

(1) HC : V_M = 50%; V_I = GND to V_{CC}.
HCT: V_M = 1.3 V; V_I = GND to 3 V.

TEST CIRCUIT AND WAVEFORMS

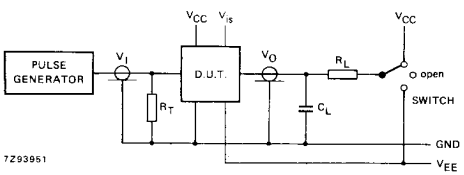


Fig. 20 Test circuit for measuring AC performance.

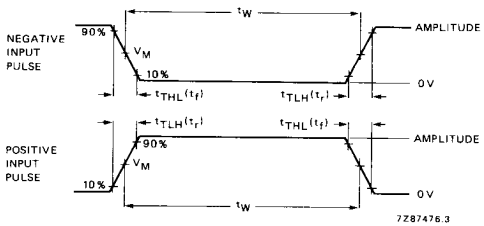


Fig. 21 Input pulse definitions.

Conditions

TEST	SWITCH	V_{is}
t_{PZH}	V_{EE}	V_{CC}
t_{PZL}	V_{CC}	V_{EE}
t_{PHZ}	V_{EE}	V_{CC}
t_{PLZ}	V_{CC}	V_{EE}
others	open	pulse

FAMILY	AMPLITUDE	V_M	t_r; t_f	
			f_{max}; PULSE WIDTH	OTHER
74HC	V_{CC}	50%	< 2 ns	6 ns
74HCT	3.0 V	1.3 V	< 2 ns	6 ns

Definitions for Figs 20 and 21:

C_L = load capacitance including jig and probe capacitance (see AC CHARACTERISTICS for values).

R_T = termination resistance should be equal to the output impedance Z_O of the pulse generator.

t_r = t_f = 6 ns; when measuring f_{max}, there is no constraint on t_r, t_f with 50% duty factor.